



**ELECTRONIC COPY**

LG786645495  
Report verification at igi.org



April 10, 2026

IGI Report Number **LG786645495**

Description **LABORATORY GROWN DIAMOND**

Shape and Cutting Style **OVAL BRILLIANT**

Measurements **9.19 X 6.54 X 4.10 MM**

**GRADING RESULTS**

Carat Weight **1.53 CARAT**

Color Grade **D**

Clarity Grade **VVS 2**

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**GRADING RESULTS**

Carat Weight **1.53 CARAT**

Color Grade **D**

Clarity Grade **VVS 2**

**ADDITIONAL GRADING INFORMATION**

Polish **EXCELLENT**

Symmetry **EXCELLENT**

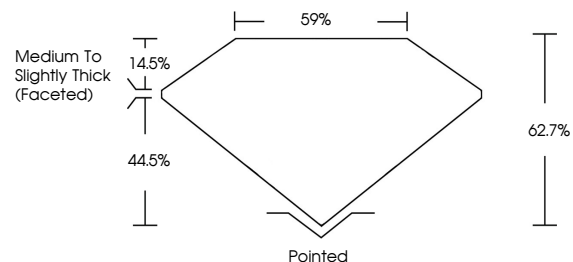
Fluorescence **NONE**

Inscription(s) **LG786645495**

Comments: As Grown - No indication of post-growth treatment.

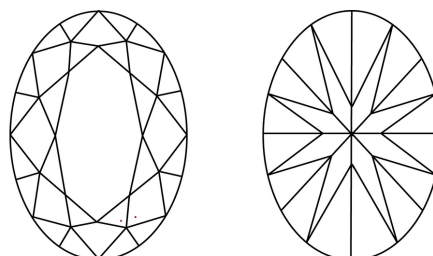
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process. Type II

**PROPORTIONS**



Sample Image Used

**CLARITY CHARACTERISTICS**



**KEY TO SYMBOLS**

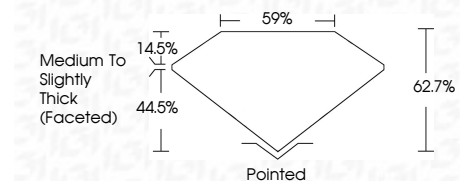
Red symbols indicate internal characteristics.  
Green symbols indicate external characteristics.

**COLOR**

D E F G H I J Faint Very Light Light

**CLARITY**

FL	IF	VVS <sup>1-2</sup>	VS <sup>1-2</sup>	SI <sup>1-2</sup>	I <sup>1-3</sup>
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included



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**IGI**



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IGI Report No LG786645495  
OVAL BRILLIANT  
9.19 X 6.54 X 4.10 MM  
1.53 CARAT  
D  
VVS 2  
62.7%  
59%  
Medium to Slightly Thick (Faceted)  
Pointed  
EXCELLENT  
EXCELLENT  
NONE  
None  
IGI LG786645495  
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